

DOCKET NO: 239515US2



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

RE APPLICATION OF :
KEISUKE YONEHAMA, ET AL. : EXAMINER: OWENS, D.
SERIAL NO: 10/602,595 :
FILED: JUNE 25, 2003 : GROUP ART UNIT: 2811
FOR: A SEMICONDUCTOR MEMORY :
DEVICE HAVING A GATE ELECTRODE
AND A DIFFUSION LAYER AND A
MANUFACTURING METHOD THEREOF

AMENDMENT FILED CONCURRENTLY WITH AN RCE

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated February 15, 2005, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Abstract begin on page 5 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 7 of this paper.

Remarks begin on page 14 of this paper.